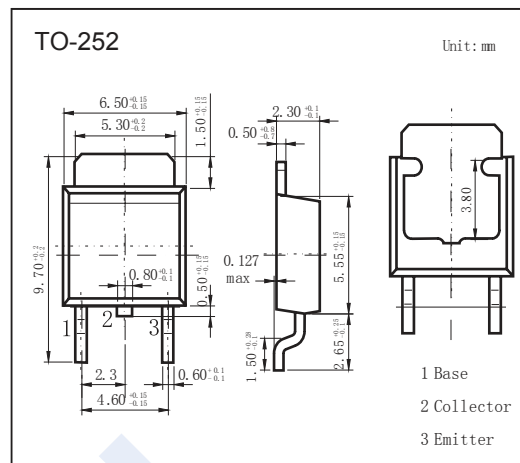


PNP Transistors

2SB1205

■ Features

- Low collector-to-emitter saturation voltage.
- High current and high fr
- Fast switching time.

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector - Base Voltage	V_{CB0}	-25	V
Collector - Emitter Voltage	V_{CE0}	-20	
Emitter - Base Voltage	V_{EB0}	-5	
Collector Current - Continuous	I_C	-5	A
Collector Current - Pulse	I_{CP}	-8	
Base Current	I_B	-0.5	
Collector Power Dissipation $T_c = 25^\circ\text{C}$	P_C	10	W
		1	
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature range	T_{stg}	-55 to 150	

■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector- base breakdown voltage	V_{CB0}	$I_C = -100\ \mu\text{A}$, $I_E = 0$	-25			V
Collector- emitter breakdown voltage	V_{CE0}	$I_C = -1\ \text{mA}$, $R_{BE} = \infty$	-20			
Emitter - base breakdown voltage	V_{EB0}	$I_E = -100\ \mu\text{A}$, $I_C = 0$	-5			
Collector-base cut-off current	I_{CBO}	$V_{CB} = -20\text{V}$, $I_E = 0$			-0.5	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = -4\text{V}$, $I_C = 0$			-0.5	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -3\ \text{A}$, $I_B = -60\text{mA}$		-0.25	-0.5	V
Base - emitter saturation voltage	$V_{BE(sat)}$	$I_C = -3\ \text{A}$, $I_B = -60\text{mA}$		-1	-1.3	
DC current gain	h_{FE}	$V_{CE} = -2\text{V}$, $I_C = -500\ \text{mA}$	100		400	
		$V_{CE} = -2\text{V}$, $I_C = -4\ \text{A}$	60			
Turn-ON Time	t_{on}	See specified Test Circuit		40		ns
Storage Time	t_{stg}			200		
Fall Time	t_f			10		
Collector output capacitance	C_{ob}	$V_{CB} = -10\text{V}$, $I_E = 0$, $f = 1\text{MHz}$		60		pF
Transition frequency	f_T	$V_{CE} = -5\text{V}$, $I_C = -200\ \text{mA}$		320		MHz

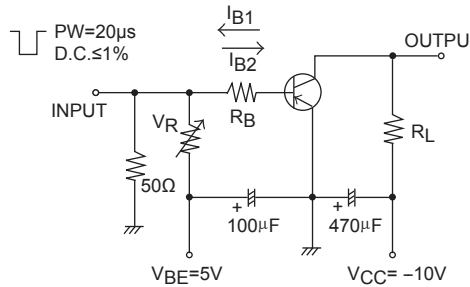
■ Classification of $h_{FE}(1)$

Type	2SB1205-R	2SB1205-S	2SB1205-T
Range	100-200	140-280	200-400

PNP Transistors

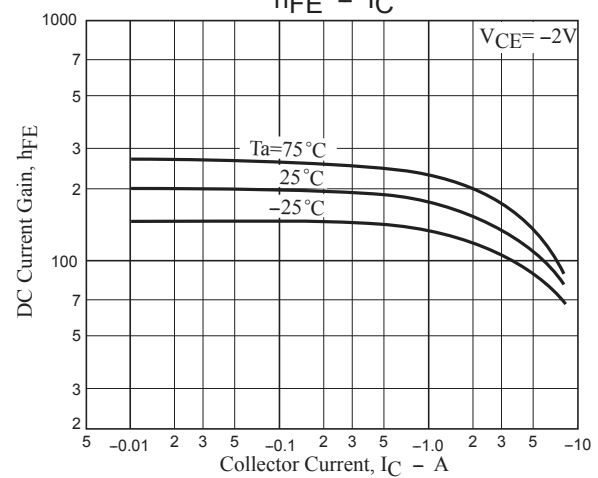
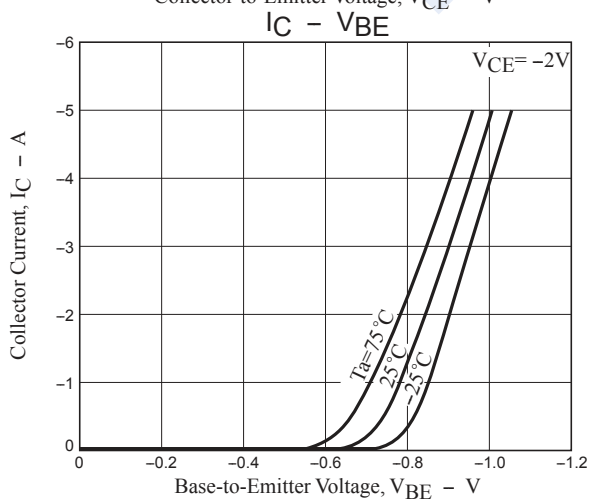
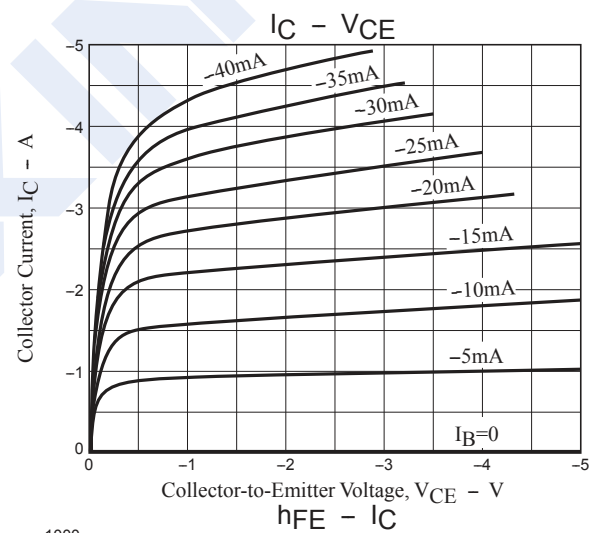
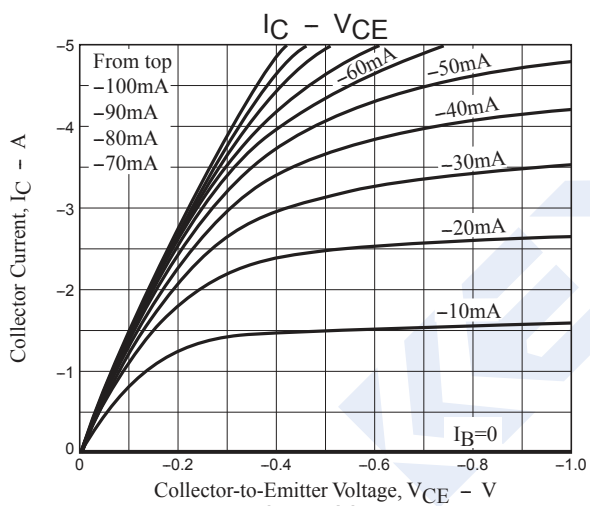
2SB1205

Switching Time Test Circuit



$$I_C = 10I_{B1} = -10I_{B2} = -2A$$

■ Typical Characteristics



PNP Transistors

2SB1205

■ Typical Characteristics

